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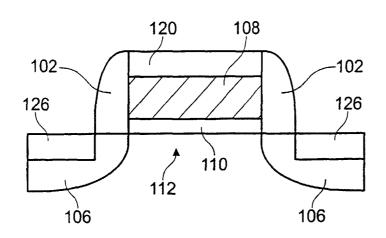
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For two-letter codes and other abbreviations, refer to the "Guidance Notes on Codes and Abbreviations" appearing at the beginning of each regular issue of the PCT Gazette.

(54) Title: AMORPHIZATION OF SUBSTRATE TO PREVENT SILICIDE ENCROACHMENT INTO CHANNEL REGION OF FIELD EFFECT TRANSISTOR



(57) Abstract: A MOSFET includes silicided source/drain terminals (106) and a substantially metal-free channel region (112), wherein the metal is characterized in that it diffuses more easily into the material of the substrate which contains the source/drain terminals (106) than the material of the substrate diffuses into the metal. In a further aspect of the present invention, a portion of the source/drain terminals (106) of a MOSFET are converted to an amorphous material (122) prior to being reacted with a metal.

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INTERNATIONAL SEARCH REPORT

International application No. PCT/US99/26865

A. CLASSIFICATION OF SUBJECT MATTER							
PC(6) : HO1L 29/76 US CL : 257/385, 386, 387, 388							
According to International Patent Classification (IPC) or to both national classification and IPC							
B. FIELDS SEARCHED Minimum documentation searched (classification system followed by classification symbols)							
U.S.: 257/385, 386, 387, 388							
Documentation searched other than minimum documentation to the extent that such documents are included in the fields searched							
Electronic data base consulted during the international search (name of data base and, where practicable, search terms used)							
C. DOC	CUMENTS CONSIDERED TO BE RELEVANT						
Category*	Citation of document, with indication, where a	appropriate, of the relevant passages	Relevant to claim No.				
X	US 5,807,770 A (MINEJI) 15 Septer lines 6-28.	mber 1998 (15.09.98), col. 5,	1-6, 10, 11, 15-19				
X	US 5,766,997 A (TAKEUCHI) 16 I lines 44-68.	June 1998 (16.06.98), col. 6,	1-17, 19, 20				
X	US 5,899,720 A (MIKAGI) 04 May 2-22.	1999 (04.05.99), col. 5, lines	1-11, 13, 19, 20				
X	US 5,691,212 A (TSAI et.al.) 25 N 5,lines 14-67.	1-11, 13, 15, 18- 20					
X	US 5,710,450 A (CHAU et.al.) 20 J 3, lines 4-65.	1-6					
X	US 6,010,936 A (SON) 04 January 20 58.	000 (04.01.00), col 3, lines 3-	1-6, 8				
X Further documents are listed in the continuation of Box C. See patent family annex.							
•	ecial categories of cited documents:	"T" later document published after the inter date and not in conflict with the applica	tion but cited to understand the				
to i	the document published on or after the international filing date	"X" document of particular relevance; the	claimed invention cannot be				
"L" document which may throw doubts on priority claim(s) or which is cited to establish the publication date of another citation or other		considered novel or cannot be considered to involve an inventive step when the document is taken alone					
special reason (as specified) Odocument referring to an oral disclosure, use, exhibition or other		"Y" document of particular relevance; the considered to involve an inventive combined with one or more other such	step when the document is documents, such combination				
"P" doo	ans cument published prior to the international filing date but later than priority date claimed	being obvious to a person skilled in the "&" document member of the same patent to					
		Date of mailing of the international sear	rch report				
02 FEBRUARY 2000		18 JUL 2000	,				
Name and mailing address of the ISA/US Commissioner of Patents and Trademarks		Authorized officer					
Box PCT Washington, D.C. 20231		EDGARDO ORTIZ					
Facsimile N	o. (703) 305-3230	Telephone No. (703) 308 - 0956					

INTERNATIONAL SEARCH REPORT

International application No. PCT/US99/26865

C (Continuation). DOCUMENTS CONSIDERED TO BE RELEVANT					
Category*	Citation of document, with indication, where appropriate, of the relevant	ant passages	Relevant to claim No.		
Y	JP 405136398 A (HAYASHIDA) 06 June 1993 (06.06 abstract	5.93),	1-6		
Y	JP 362122173 A (IMAOKA) 03 June 1987 (03.06.87).	, abstract	1-6		

INTERNATIONAL SEARCH REPORT

International application No. PCT/US99/26865

Box	I Observations w	nere certain claims were found unsearchable (Continuation of item 1 of first sheet)	
This i	nternational report h	as not been established in respect of certain claims under Article 17(2)(a) for the following reasons:	
1. [Claims Nos.: because they r	elate to subject matter not required to be searched by this Authority, namely:	
2. [late to parts of the international application that do not comply with the prescribed requirements to such no meaningful international search can be carried out, specifically:	
3. [Claims Nos.: because they ar	e dependent claims and are not drafted in accordance with the second and third sentences of Rule 6.4(a).	
Box I	I Observations w	nere unity of invention is lacking (Continuation of item 2 of first sheet)	
This 1	International Search	ing Authority found multiple inventions in this international application, as follows:	
	Please See Extra S	heet.	
1.	As all required claims.	additional search fees were timely paid by the applicant, this international search report covers all searchai	ble
2.	As all searchab	le claims could be searched without effort justifying an additional fee, this Authority did not invite payme al fee.	ent
3.		f the required additional search fees were timely paid by the applicant, this international search report covers for which fees were paid, specifically claims Nos.:	ers
4.		ditional search fees were timely paid by the applicant. Consequently, this international search report invention first mentioned in the claims; it is covered by claims Nos.:	is
Rema	rk on Protest	The additional search fees were accompanied by the applicant's protest. X No protest accompanied the payment of additional search fees.	

INTERNALIONAL SEARCH REPORT

International application No. PCT/US99/26865

BOX'II. OBSERVATIONS WHERE UNITY OF INVENTION WAS LACKING This ISA found multiple inventions as follows:

This application contains the following inventions or groups of inventions which are not so linked as to form a single inventive concept under PCT Rule 13.1. In order for all inventions to be searched, the appropriate additional search fees must be paid.

Group I, claim(s)1-18, drawn to a method of forming a transistor. Group II, claim(s)19-20, drawn to a field effect semiconductor device.

The inventions listed as Groups I and II do not relate to a single inventive concept under PCT Rule 13.1 because, under PCT Rule 13.2, they lack the same or corresponding special technical features for the following reasons: The claims relating to a method of forming a transistor contain the special technical feature consisting of an amorphousportion on the source/drain regions, whereas the claims relating to the field effect semiconductor device do not include the special technical feature described.